# High Voltage Transistor





#### Features:

- Device with breakdown voltages of 160V minimum, for applications requiring relatively low collector current, such as lamp drivers and neon tubes
- NPN epitaxial planar silicon transistor
- Designed for General Purpose Applications Requiring High Breakdown Voltages, Low Saturation Voltages and Low Capacitance



Pin Configuration:

- 1. Collector
- 2. Base
- 3. Emitter

### **Absolute Maximum Ratings**

Parameters	Symbol	Value	Units
Collector Emitter Voltage	V <sub>CEO</sub>	400	
Collector Base Voltage	V <sub>CBO</sub>	500	V
Emitter Base Voltage	V <sub>EBO</sub>	6	
Collector Current Continuous	I <sub>c</sub>	300	mA
Power Dissipation at $T_a = 25^{\circ}C$ $T_C = 25^{\circ}C$	P <sub>TA</sub> P <sub>TC</sub>	625 1.5	mW W
Operating and Storage Junction Temperature Range	T <sub>j</sub> , T <sub>stg</sub>	-55 to +150	°C

### **Thermal Resistance**

Junction to Ambient	R <sub>th (j-a)</sub>	200	°C/W
Junction to Case	R <sub>th (j-c)</sub>	83.3	C/VV

## Electrical Characteristics ( $T_a = 25$ °C unless otherwise specified)

Parameters	Symbol	Test Condition	Minimum	Units
Collector-Emitter Voltage	V <sub>CEO</sub> * V <sub>CES</sub>	$I_{C} = 1 \text{mA}, I_{B} = 0$ $I_{C} = 100 \mu \text{A}, V_{BE} = 0$	>400 >500	
Collector-Base Voltage	V <sub>CBO</sub>	$I_{C} = 100 \mu A, I_{E} = 0$	>500	V
Emitter-Base Voltage	V <sub>EBO</sub>	$I_{E} = 10 \mu A, I_{C} = 0$	>6	
Collector-Cut off Current	I <sub>CBO</sub>	$V_{CB} = 400V, I_{E} = 0$ $V_{CE} = 400V, I_{B} = 0$	<100 <500	nA

<sup>\*</sup>Pulse Test: Pulse Width = 300µs, Duty Cycle = 2%.

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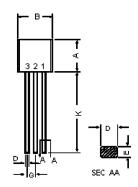
## Electrical Characteristics (T<sub>a</sub> = 25°C unless otherwise specified)

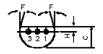
Parameters	Symbol	Test Condition	Minimum	Units
Emitter-Cut off Current	I <sub>EBO</sub>	V <sub>EB</sub> = 4V, I <sub>C</sub> = 0	<100	nA
DC Current Gain	h <sub>FE</sub> *	$I_C = 1mA, V_{CE} = 10V$ $I_C = 10mA, V_{CE} = 10V$ $I_C = 50mA, V_{CE} = 10V$	>40 50-200 >45	-
Collector Emitter Saturation Voltage	V <sub>CE (sat)</sub> *	$I_{C} = 1 \text{mA}, I_{B} = 0.1 \text{mA}$ $I_{C} = 10 \text{mA}, I_{B} = 1 \text{mA}$ $I_{C} = 50 \text{mA}, I_{B} = 5 \text{mA}$	<0.4 <0.5 <0.75	V
Base Emitter Saturation Voltage	V <sub>BE (sat)</sub> *	I <sub>C</sub> = 10mA, I <sub>B</sub> = 1mA	<0.75	

#### **Dynamic Characteristics**

Output Capacitance	C <sub>ob</sub>	$V_{CB} = 20V, I_{E} = 0,$ f = 1MHz	<7	pF
Input Capacitance	C <sub>ib</sub>	$V_{EB} = 0.5V, I_{C} = 0,$ f = 1MHz	<130	рг
Small Signal Current Gain	h <sub>fe</sub>	$I_C = 10$ mA, $V_{CE} = 10$ V, f = 10MHz	>2	-

<sup>\*</sup>Pulse Test : Pulse Width = 300µs, Duty Cycle = 2%.





Dimensions	Minimum	Maximum	
А	4.32	5.33	
В	4.45	5.2	
С	3.18	4.19	
D	0.41	0.55	
E	0.35	0.5	
F	5°		
G	1 11	1.4	
Н	1.14	1.53	
K	12.7	-	

Dimensions : Millimetres

### Pin Configuration:

- 1. Collector
- 2. Base
- 3. Emitter

### **Part Number Table**

Description	Part Number
Transistor, NPN, TO-92	MPSA44

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